

RV1S2281A

OPERATING AMBIENT TEMPERATURE 115°C, 4-PIN SSOP WITH 8.2mm CREEPAGE DISTANCE (LSSOP) PHOTOCOUPLER R08DS0185EJ0100 Rev.1.00 Nov 11,2019

DESCRIPTION

The RV1S2281A is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor.

This package is very small and thin with long creepage distance(8.2mm).

This small product is suitable for various interface circuits which require surface mounting and high-density mounting.

FEATURES

- Small and long creepage (8.2 mm, LSSOP)
- Operating ambient temperature: 115°C
- High isolation voltage (BV = 5000 Vr.m.s.)
- Embossed tape product : RV1S2281ACCSP-10Yx#KC0 : 3500 pcs/reel
- Pb-Free product
- Safety standard

• UL : UL1577, Double protection

•CSA : CAN/CSA-C22.2 No.62368-1, Reinforced insulation

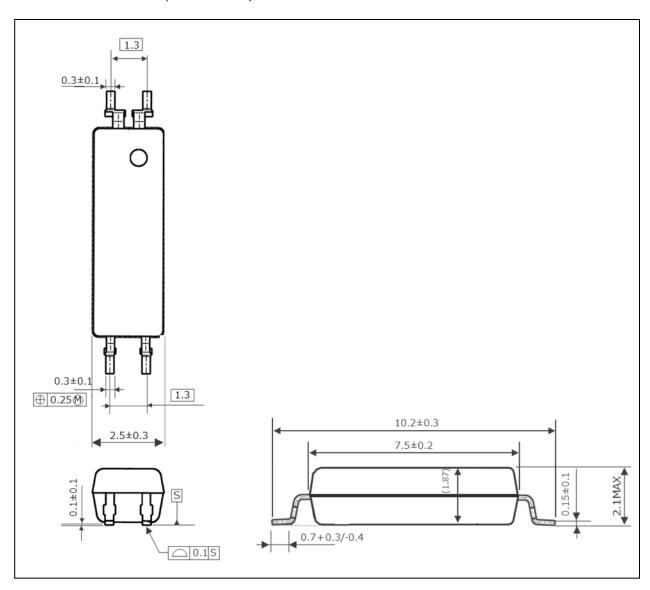
•VDE : DIN EN 60747-5-5 (Option)

PIN CONNECTION (Top View) 4 3 1. Anode 2. Cathode 3. Emitter 4. Collector

APPLICATIONS

- Robot controller
- Industrial inverter
- AC Servo
- Programmable logic controller
- Measurement equipment
- Power supply

PACKAGE DIMENSIONS (UNIT: mm)

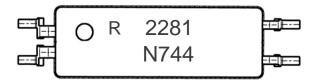


Weight: 0.075g (Typ.)

PHOTOCOUPLER CONSTRUCTIONS

| Parameter | UNIT (MIN.) |
|--------------------|-------------|
| Air Distance | 8.2 mm |
| Creepage Distance | 8.2 mm |
| Isolation Distance | 0.15 mm |

MARKING EXAMPLE



| F | र | An initial of "Renesas" | | An initial of "Renesas" | |
|------|-----|-----------------------------------|--|-------------------------|--|
| 22 | 81 | Product Part Number * | | | |
| | | No.1 pin Mark | | | |
| N744 | N | Rank Code | | | |
| | 744 | Assembly Lot | | | |
| | | 7 Last one-digit of Assembly Year | | | |
| | | 44 Weekly Serial Code | | | |

*) Applicable type numbers listed below

RV1S 2281 ACCSP-10Yx

Marking type number. " RV1S" and "ACCSP-10Yx" " are omitted from original type number

ORDERING INFORMATION

| Part Number | Order Number | Solder Plating Specification*1 | Packing Style | Safety Standard Approval | Application Part Number*2 |
|------------------------|----------------------------|-----------------------------------|-----------------------------|------------------------------|---------------------------------|
| RV1S2281ACCSP -10YC | RV1S2281ACCSP -10YC#SC0 | Pb-Free and Halogen Free | 20 pcs(Tape 20 pcs cut) | Standard products (UL, CSA | RV1S2281A |
| | RV1S2281ACCSP -10YC#KC0 | (Ni/Pd/Au) | Embossed Tape 3500 pcs/reel | approved) | |
| RV1S2281ACCSP -10YV | RV1S2281ACCSP -10YV#SC0 | | 20 pcs(Tape 20 pcs cut) | UL, CSA, DIN EN 60747-5-5 | |
| | RV1S2281ACCSP -10YV#KC0 | | Embossed Tape 3500 pcs/reel | approved | |

Notes:*1. When specifying CTR rank, please add "/CTR rank" after Order Number.

ex. L rank: RV1S2281ACCSP-10YC#SC0/L

Notes:*2. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

| Parameter | | Symbol | Ratings | Unit | |
|-------------------|------------------------------|---------------------|------------|---------|--|
| Diode | Forward Current (DC) | l _F | 30 | mA | |
| | Reverse Voltage | VR | 6 | V | |
| | Power Dissipation Derating*1 | ⊿P _D /°C | 0.6 | mW/°C | |
| | Power Dissipation | P _D | 60 | mW | |
| | Peak Forward Current*2 | I _{FP} | 0.5 | А | |
| Transistor | Collector to Emitter Voltage | Vceo | 80 | V | |
| | Emitter to Collector Voltage | V _{ECO} | 5 | V | |
| Collector Current | | lc | 30 | mA | |
| | Power Dissipation Derating*1 | ⊿Pc/°C | 1.2 | mW/°C | |
| | Power Dissipation | Pc | 120 | mW | |
| Isolation Vo | oltage*3 | BV | 5000 | Vr.m.s. | |
| Operating A | Ambient Temperature | TA | -40 ~ +115 | °C | |
| Storage Te | mperature | T _{stg} | -40 ~ +125 | °C | |

^{*1} Derating from $T_A = 25^{\circ}C$

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

| | Parameter | Symbol | Conditions | MIN. | TYP. | MAX. | Unit |
|------------|-----------------------------------|------------------|---|------------------|------|------|---------|
| Diode | Forward Voltage | VF | I _F = 5 mA | | 1.15 | 1.4 | V |
| | Reverse Current | I _R | V _R = 5 V | | | 5 | μ A |
| | Terminal Capacitance | Ct | V = 0 V, f = 1 MHz | | 10 | | pF |
| Transistor | Collector to Emitter Dark Current | Iceo | I _F =0mA, V _{CE} =80V | | | 100 | nA |
| Coupled | Current Transfer Ratio | CTR | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$ | 50 | 100 | 400 | % |
| | (Ic/I _F) *1 | | I _F = 1 mA, V _{CE} = 5 V | 10 | 50 | | |
| | Collector Saturation Voltage | VCE (sat) | I _F = 10 mA, I _C = 2 mA | | | 0.3 | V |
| | Isolation Resistance | R _{I-O} | $V_{I-O} = 1kV_{DC}$ | 10 ¹¹ | | | Ω |
| | Isolation Capacitance | C _{I-O} | V = 0 V, f = 1 MHz | | 0.4 | | pF |
| | Rise Time*2 | t _r | $V_{CC} = 5 \text{ V}, I_{C} = 2 \text{ mA}$ | | 4 | | μS |
| | Fall Time*2 | t _f | $R_L = 100 \Omega$ | | 5 | | |

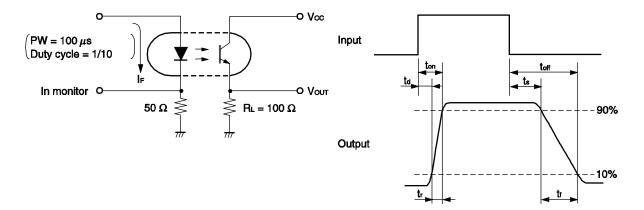
*1. CTR rank

| CTR rank | CTR(%) | Condition |
|----------|----------|--|
| N | 50 ~ 400 | I _F =5mA, V _{CE} =5V |
| | 10 ~ | I _F =1mA, V _{CE} =5V |
| M | 50~150 | I _F =5mA, V _{CE} =5V |
| | 10 ~ | I _F =1mA, V _{CE} =5V |
| L | 100~300 | I _F =5mA, V _{CE} =5V |
| | 20 ~ | I _F =1mA, V _{CE} =5V |
| W | 130~260 | I _F =5mA, V _{CE} =5V |
| | 20 ~ | I _F =1mA, V _{CE} =5V |

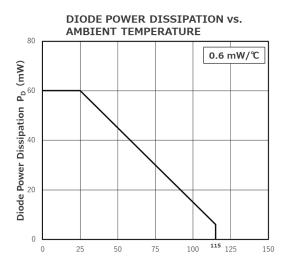
^{*2} PW = 100 μ s, Duty Cycle = 1%

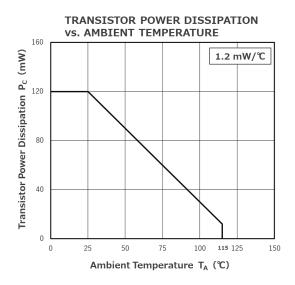
^{*3} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

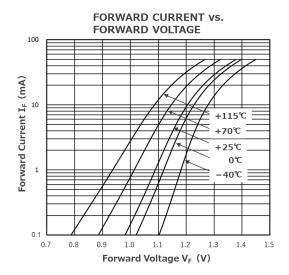
*2. Test circuit for switching time

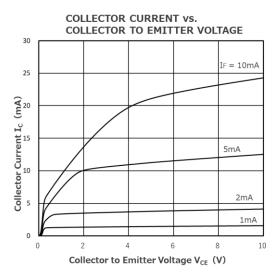


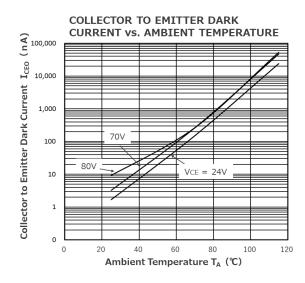
TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

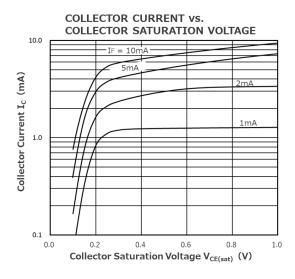






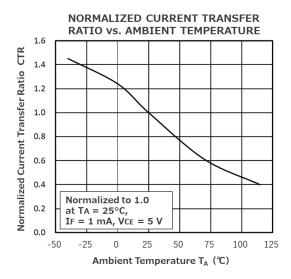


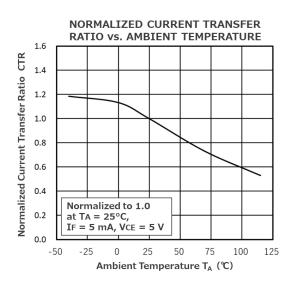


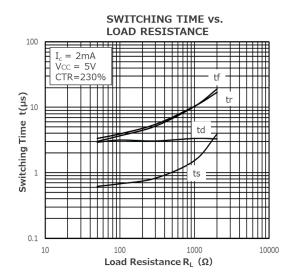


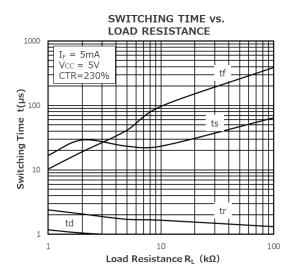
Remark The graphs indicate nominal characteristics.

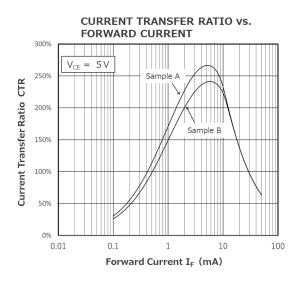
TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified)

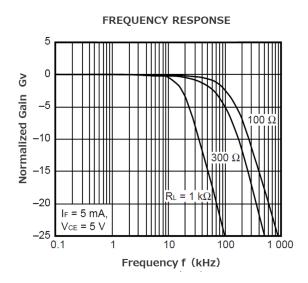






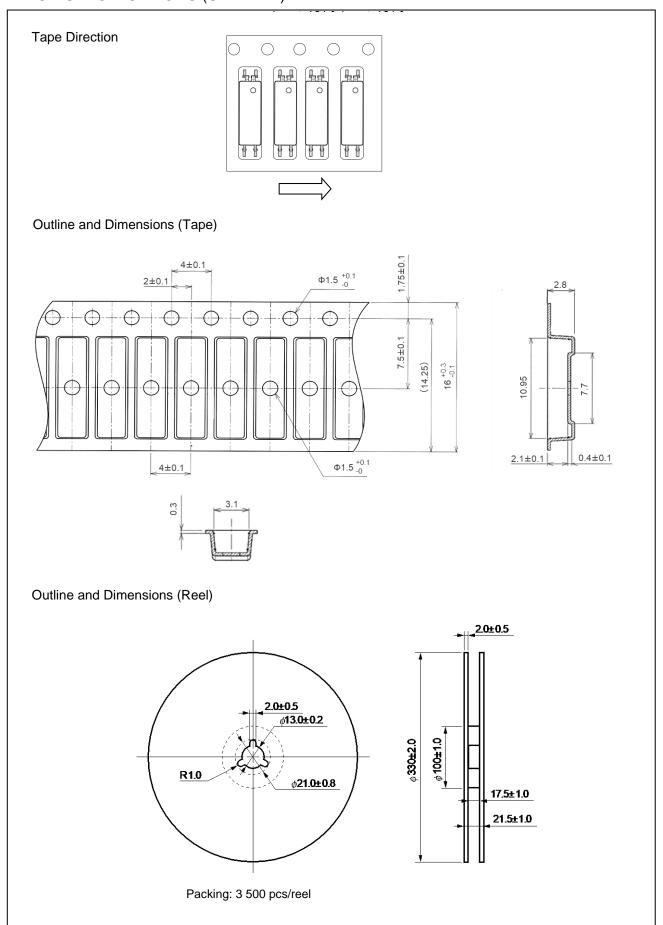




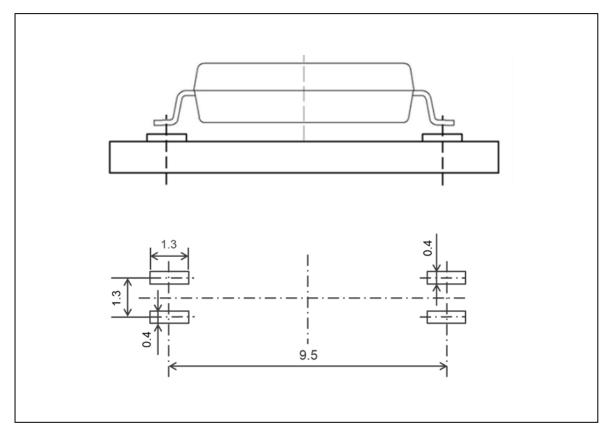


Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT : mm)



Remark All dimensions in this figure must be evaluated before use.

NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

Peak reflow temperature 260°C or below (package surface temperature)

Time of peak reflow temperature 10 seconds or less Time of temperature higher than 220°C 60 seconds or less Time to preheat temperature from 120 to 180°C 120±30 s

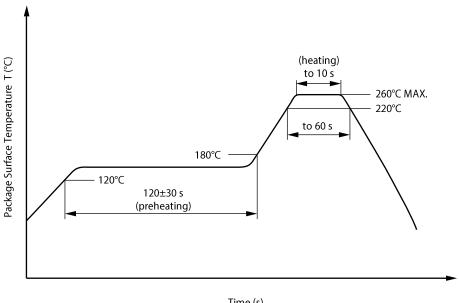
Number of reflows Three

Flux Rosin flux containing small amount of chlorine (The

flux with a maximum chlorine content of 0.2 Wt% is

recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

Temperature 260°C or below (molten solder temperature)

Time 10 seconds or less

Preheating conditions 120°C or below (package surface temperature)

Number of times One (Allowed to be dipped in solder including plastic mold portion.)

Flux Rosin flux containing small amount of chlorine (The flux with a maximum

chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

Peak Temperature (lead part temperature) 350°C or below Time (each pins) 3 seconds or less

Flux Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

Flux Cleaning

Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.

Do not use fixing agents or coatings containing halogen-based substances.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collectoremitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

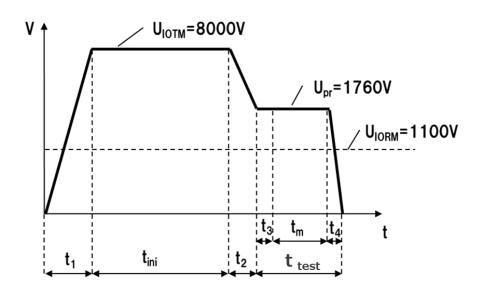
USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

| Parameter | Symbol | Rating | Unit |
|---|--------------------------|--------------------------------------|--|
| Climatic test class (IEC 60068-1/DIN EN 60068-1) | | 40/115/21 | |
| Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.6 \times U_{\text{IORM}}, P_d < 5 \text{pC}$ | UIORM U _{pr} | 1 100 1 760 | V _{peak} V _{peak} |
| Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}, P_d < 5 \; pC$ | U _{pr} | 2 063 | V_{peak} |
| Highest permissible overvoltage | Uютм | 8 000 | V _{peak} |
| Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1)) | | 2 | |
| Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11)) | CTI | 400 | |
| Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1)) | | П | |
| Storage temperature range | T _{stg} | -40~+125 | °C |
| Operating temperature range | T _A | -40~+115 | °C |
| Isolation resistance, minimum value VIO = 500 V dc at TA = 25°C VIO = 500 V dc at TA MAX. at least 100°C | Ris MIN. Ris MIN. | 10 ¹² 10 ¹¹ | Ω |
| Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I _F , Psi = 0) | Tsi Isi | 175 400 | °C mA |
| Power (output or total power dissipation) Isolation resistance $V_{IO} = 500 \text{ V}$ dc at $T_A = T_{SI}$ | Psi Ris MIN. | 700 10 ⁹ | mW $Ω$ |

Method a) Destructive Test, Type and Sample Test



 $t_1,t_2=1$ to 10 sec

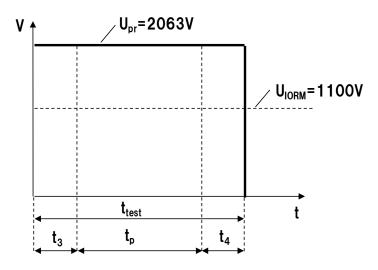
 $t_3, t_4 = 1 \text{ sec}$

 $t_{m (PARTIAL DISCHARGE)} = 10 sec$

 t_{test} =12 sec

t_{ini}=60 sec

Method b) Non-destructive Test, 100% Production Test



 t_3,t_4 =0.1 sec $t_{p (PARTIAL DISCHARGE)}$ =1.0 sec t_{test} =1.2 sec

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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(Rev.4.0-1 November 2017)



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